





ZXTN25100BFH

### 100V NPN LOW SATURATION TRANSISTOR IN SOT23

### **Features**

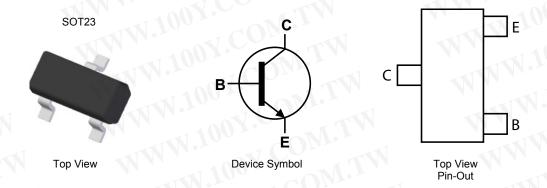
- BV<sub>CEO</sub> > 100V
- BV<sub>CEX</sub> > 170V forward blocking voltage
- BV<sub>ECO</sub> > 6V reverse blocking voltage
- I<sub>C</sub> = 3A high Continuous Collector Current
- Low saturation voltage, V<sub>CE(SAT)</sub> < 80mV @1A</li>
- R<sub>CE(SAT)</sub> = 67mΩ for a low equivalent On-Resistance
- 1.25W Power dissipation
- h<sub>FE</sub> specified up to 3A for high current gain hold up
- Complementary PNP Type: ZXTP25100BFH
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (approximate)

### **Applications**

- Lamp relay and solenoid drivers
- General switching in automotive and industrial applications
- Motor drive and control



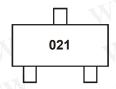
## Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25100BFHTA	021	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</li>
- 4. For packaging details, go to our website at http://www.diodes.com.

# **Marking Information**

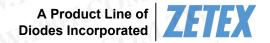


021 = Product Type Marking Code

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### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	170	V
Collector-Emitter Voltage (Forward Blocking)	V <sub>CEX</sub>	170	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage (Reverse Blocking)	V <sub>ECO</sub>	6	V
Emitter-Base Voltage	V <sub>EBO</sub>	7-1	V
Continuous Collector Current	Ic	3	A
Peak Pulse Current (Note 5)	I <sub>CM</sub>	9	Α

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	47 CU:	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 5)	P <sub>D</sub>	0.73 5.84	mW
Power Dissipation Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.05 8.4	mW
Power Dissipation Linear Derating Factor	(Note 7)	P <sub>D</sub>	1.25 9.6	mW
Power Dissipation Linear Derating Factor	(Note 8)	P <sub>D</sub>	1.81 14.5	mW
Thermal Resistance, Junction to Ambient	(Note 5)	R <sub>0JA</sub>	171	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	119	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>0JA</sub>	100	°C/W
Thermal Resistance, Junction to Ambient	(Note 8)	R <sub>0JA</sub>	69	°C/W
Thermal Resistance, Junction to Leads (Note 9)		Rejl	74.96	°C/W
Operating and Storage Temperature Range	T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C	

## ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

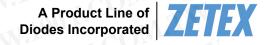
Notes:

- 5. For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as note (5), except mounted on 25mm x 25mm x 1.6mm FR4 PCB with 2 oz copper. 7. Same as note (5), except mounted on 50mm x 50mm x 1.6mm FR4 PCB with 2 oz copper.

- 8. Same as note (7), except measured at t < 5secs.
  9. Thermal resistance from junction to solder-point (at the end of collector lead).
- 10.Refer to JEDEC specification JESD22-A114 and JESD22-A115.

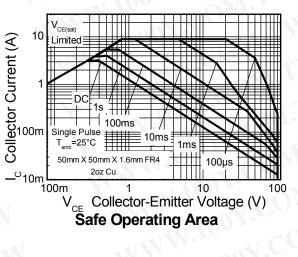


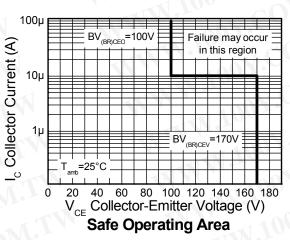
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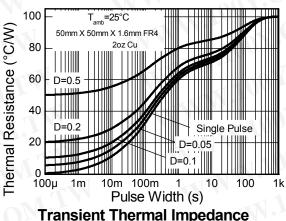


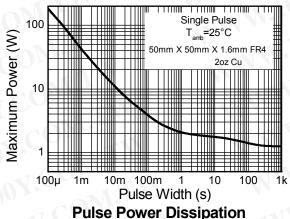
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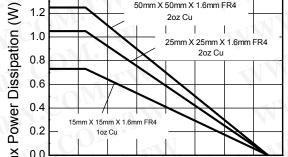
## Thermal Characteristics and Derating information



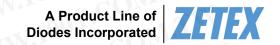












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## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	170	220	1 3 1	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Forward Blocking) (Note 11)	BV <sub>CEX</sub>	170	210		V	$I_C$ = 100μA, $R_{BE}$ < 1k $\Omega$ or -1V < $V_{BE}$ < 0.25V
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	100	120	11.	V	I <sub>C</sub> = 1mA
Emitter-Collector Breakdown Voltage (Reverse Blocking) (Note 11)	BV <sub>ECX</sub>	6	7	-	V	$I_E$ = 100μA, $R_{BC}$ < 1kΩ or 0.25V > $V_{BC}$ > -0.25V
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	6	8.4	74.7	V	I <sub>E</sub> = 100μA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8	-	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	1	<1	50 20	nA	V <sub>CB</sub> = 136V V <sub>CB</sub> = 136V, T <sub>A</sub> = +100°C
Collector Emitter Cut-off Current	I <sub>CEX</sub>	1	-	100	nA	$V_{CE}$ = 136V, $R_{BE}$ < 1k $\Omega$ or -1V < $V_{BE}$ < 0.25V
Emitter Cut-off Current	I <sub>EBO</sub>	-	<1	50	nA	V <sub>EB</sub> = 5.6V
Static Forward Current Transfer Ratio (Note 11)	h <sub>FE</sub>	100 50 -	200 85 20	300 - -	-	$I_C = 10\text{mA}, V_{CE} = 2V$ $I_C = 1A, V_{CE} = 2V$ $I_C = 3A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	W. J	40 100 70 200	55 135 80 250	mV	$I_C = 0.5A$ , $I_B = 50mA$ $I_C = 0.5A$ , $I_B = 10mA$ $I_C = 1A$ , $I_B = 100mA$ $I_C = 3A$ , $I_B = 300mA$
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	1) [2] 2.	940	1050	mV	I <sub>C</sub> = 3A, I <sub>B</sub> = 300mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(on)</sub>	-	890	1000	mV	I <sub>C</sub> = 3A, V <sub>CE</sub> = 2V
Transition Frequency	fτ	ON	160	- T	MHz	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V, f = 100MHz
Collector Output Capacitance	C <sub>obo</sub>	-	9.4	20	pF	V <sub>CB</sub> = 10V, f = 1MHz
Delay Time	t <sub>(d)</sub>		16		ns	
Rise Time	t <sub>(r)</sub>	<u> </u>	55	-	ns	$V_{CC} = 10V, I_C = 0.5A,$
Storage Time	t <sub>(s)</sub>	- /	677	7 :	ns	I <sub>B1</sub> = -I <sub>B2</sub> = 50mA
Fall Time	t <sub>(f)</sub>	17 F.	95		ns	

Notes: 11. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ 

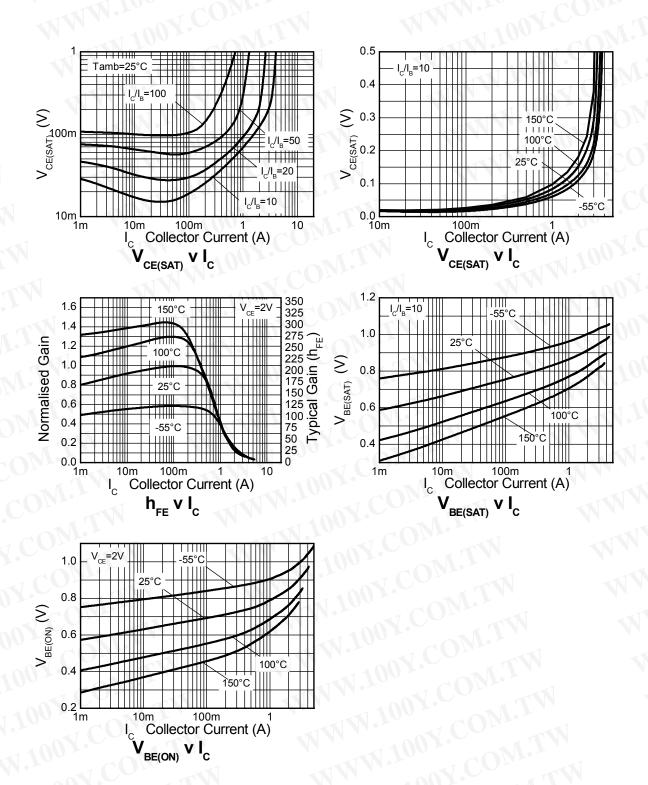
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## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



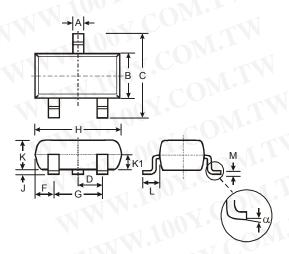


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# **Package Outline Dimensions**

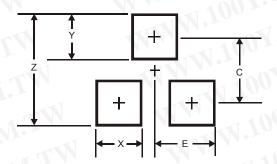
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1		0/-//	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	4 7		
All Dimensions in mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
Z	2.9			
X	0.8			
Y	0.9			
C	2.0			
ш	1.35			



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